

Ultra Low Capacitance ESD Protection Array

DESCRIPTION

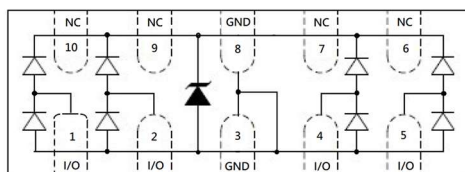
SLESD0524P is an ultra-low capacitance Transient Voltage Suppressor (TVS) designed to protection for high-speed data interfaces. With typical capacitance of 0.2pF (I/O to I/O) only, SLESD0524P is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4(±8KV contact, ±15KV air discharge), IEC61000-4-4 (electrical fast transient-EFT) (40A, 5/50ns), very fast charged device model (CDM) ESD and cable discharge event (CDE) etc.

SLESD0524P uses ultra-small DFN2510 package. Each SLESD0524P device can protect four high-speed data lines. The combined features of ultra-low capacitance, ultra-small size and high ESD robustness make SLESD0524P ideal for high-speed data ports and high-frequency lines (e.g., HDMI & DVI) applications. The low clamping voltage of the SLESD0524P guarantees a minimum stress on the protected IC.

ORDERING INFORMATION

- ✧ Device: SLESD0524P
- ✧ Package: DFN2510
- ✧ Marking: 0524P
- ✧ Material: Halogen free
- ✧ Packing: Tape & Reel
- ✧ Quantity per reel: 3,000pcs

PIN CONFIGURATION



FEATURES

- ✧ Transient protection for high-speed data lines
IEC 61000-4-2(ESD) ±20KV(Contact)
±25KV(Air)
- IEC 61000-4-4(EFT)40A(5/50ns)
Cable Discharge Event (CDE)
- ✧ Package optimized for high-speed lines
- ✧ Ultra-small package(2.5mm*1.0mm*0.5mm)
- ✧ Protects four data lines
- ✧ Low capacitance: 0.2pF (I/O to I/O)
- ✧ Low leakage current
- ✧ Low clamping voltage
- ✧ Each I/O pin can withstand over 1000 ESD strikes for ±8KV contact discharge

MACHANICAL DATA

- ✧ DFN2510 package
- ✧ Flammability Rating: UL 94V-0
- ✧ Terminal: Matte tin plated.
- ✧ Packaging: Tape and Reel
- ✧ High temperature soldering guaranteed:
260°C/10s
- ✧ Reel size: 7 inch

APPLICATIONS

- ✧ Serial ATA
- ✧ PCI Express
- ✧ Desktops, Servers and Notebooks
- ✧ MDDI Ports
- ✧ USB 2.0/3.0 Power and Data Line Protection
- ✧ Display Ports
- ✧ High Definition Multi-Media Interface (HDMI)
- ✧ Digital Visual Interface (DVI)

PACKAGE OUTLINE

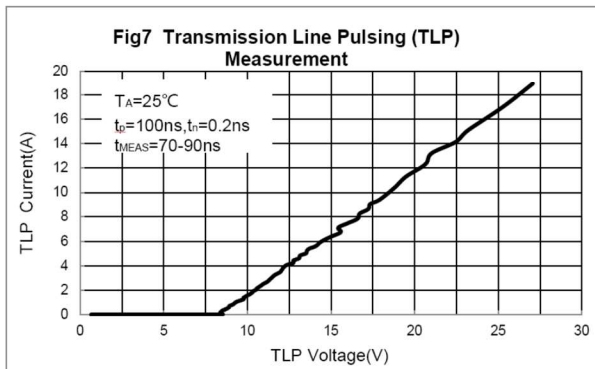
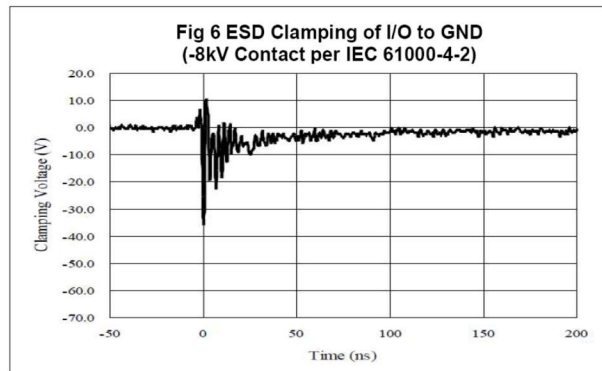
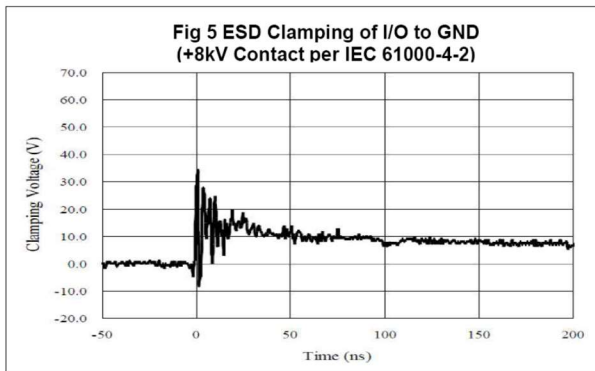
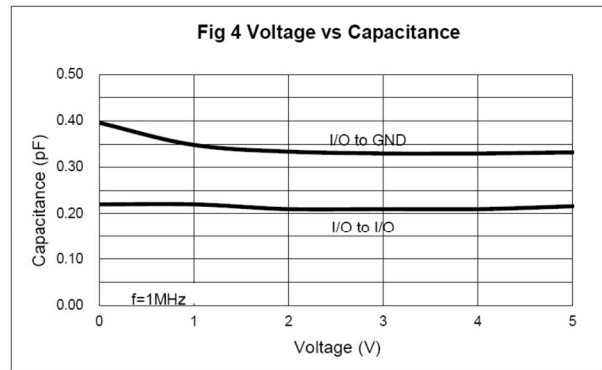
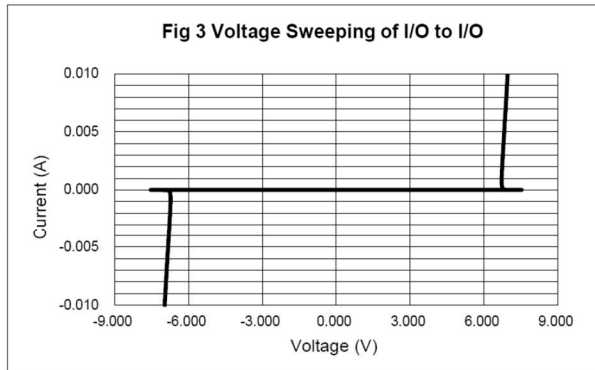
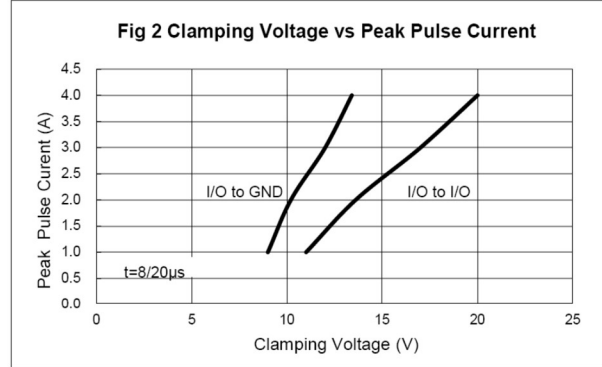
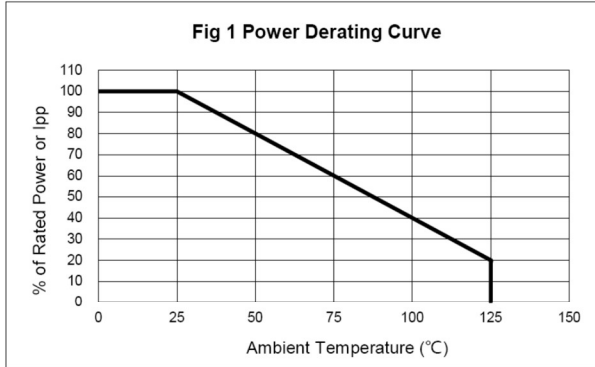


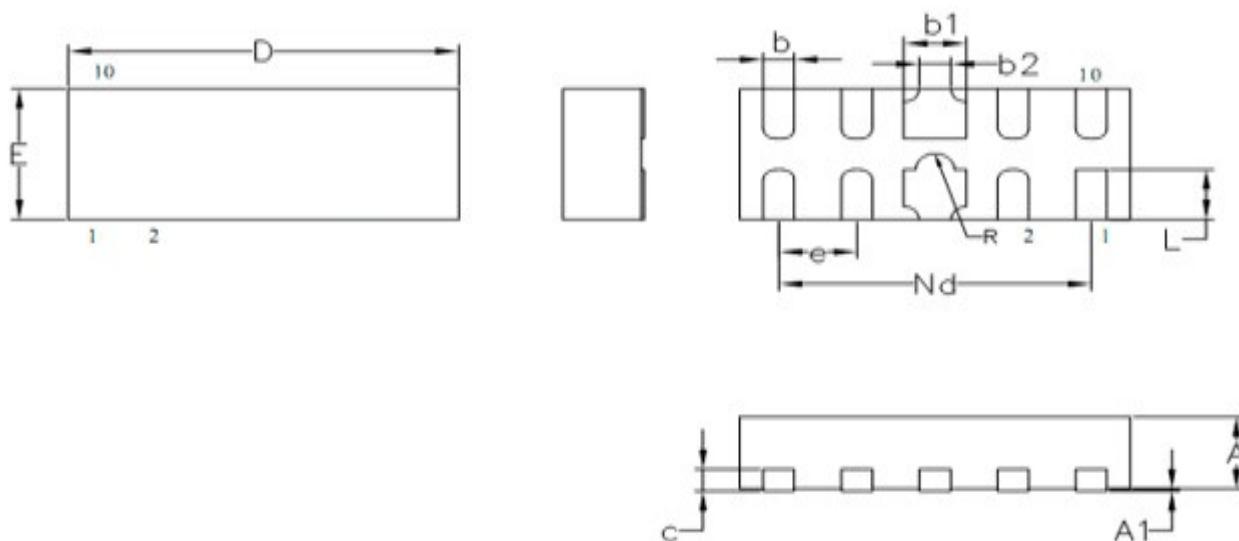
ABSOLUTE MAXIMUM RATING			
Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power (8/20μs)	60	W
V _{ESD}	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±20 ±25	kV
T _{OPT}	Operating Temperature	-55/+125	°C
T _{STG}	Storage Temperature	-55/+150	°C

ELECTRICAL CHARACTERISTICS (T _{amb} =25°C)						
Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V _{RWM}	Reverse Working Voltage	Any I/O pin to GND			5.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA Any I/O pin to GND	6.0		9.0	V
I _R	Reverse Leakage Current	V _{RWM} = 5V Any I/O pin to GND			1.0	μA
V _C	Clamping Voltage	I _{PP} = 1A, t _p = 8/20μs Any I/O pin to GND			10	V
V _C	Clamping Voltage	I _{PP} = 4A, t _p = 8/20μs Any I/O pin to GND			15	V
V _{CTLP}	TLP Clamping Voltage	I _{PP} = 8A IEC61000-4-2 Level 2 equivalent (±4kV Contact, ±8kV Air) Between I/O and GND		16		V
		I _{PP} = 16A IEC61000-4-2 Level 4 equivalent (±8kV Contact, ±16kV Air) Between I/O and GND		23		V
C _{ESD}	Parasitic Capacitance	V _R = 0V, f = 1MHz Between I/O and GND		0.4	0.5	pF
C _{ESD}	Parasitic Capacitance	V _R = 0V, f = 1MHz Between I/O and I/O		0.2	0.3	pF

Note: I/O pins are pin 1,2,4,5, GND pins are pin 3,8.

ELECTRICAL CHARACTERISTICS CURVE



DFN2510 PACKAGE OUTLINE DIMENSIONS


Symbol	Dimensions (mm)		
	Min.	Nom.	Max.
D	2.45	2.50	2.55
E	0.95	1.00	1.05
b1	0.35	0.40	0.45
b2	0.20REF		
b	0.15	0.20	0.25
L	0.33	0.38	0.43
Nd	2.00BSC		
e	0.50BSC		
R	0.10	0.125	0.15
A	0.45	0.50	0.55
c	0.15REF		
A1	0.00	-	0.05